# CMPD2005S CMPD2005SG\*

SURFACE MOUNT
DUAL, IN SERIES
HIGH VOLTAGE
SILICON SWITCHING DIODES



<sup>\*</sup> Device is *Halogen Free* by design



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# **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMPD2005S and CMPD2005SG each contain two (2) High Voltage Silicon Switching Diodes, manufactured by the epitaxial planar process, epoxy molded in a SOT-23 surface mount package, designed for applications requiring high voltage capability.

MARKING CODES: CMPD2005S: DB5 CMPD2005SG\*: 5SG

MAXIMUM RATINGS: (T <sub>A</sub> =25°C)	SYMBOL		UNITS
Continuous Reverse Voltage	$V_{R}$	300	V
Peak Repetitive Reverse Voltage	$V_{RRM}$	350	V
Average Forward Current	IO	200	mA
Continuous Forward Current	Ι <sub>Ε</sub>	225	mA
Peak Repetitive Forward Current	I <sub>FRM</sub>	625	mA
Peak Forward Surge Current, tp=1.0µs	I <sub>FSM</sub>	4.0	Α
Peak Forward Surge Current, tp=1.0s	I <sub>FSM</sub>	1.0	Α
Power Dissipation	$P_{D}$	350	mW
Operating and Storage Junction Temperature	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C
Thermal Resistance	$\Theta_{\sf JA}$	357	°C/W

# **ELECTRICAL CHARACTERISTICS PER DIODE:** $(T_A=25^{\circ}C \text{ unless otherwise noted})$

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
$I_{R}$	V <sub>R</sub> =280V		100	nA
$I_{R}$	V <sub>R</sub> =280V, T <sub>A</sub> =150°C		100	μΑ
$BV_R$	I <sub>R</sub> =100μA	350		V
$V_{F}$	I <sub>F</sub> =20mA		0.87	V
$V_{F}$	I <sub>F</sub> =100mA		1.0	V
$V_{F}$	I <sub>F</sub> =200mA		1.25	V
$c_T$	V <sub>R</sub> =0, f=1.0MHz		5.0	pF
t <sub>rr</sub>	$I_R=I_F=30$ mA, Rec. to 3.0mA, $R_L=100\Omega$		50	ns

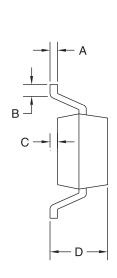
**CMPD2005S** CMPD2005SG\*

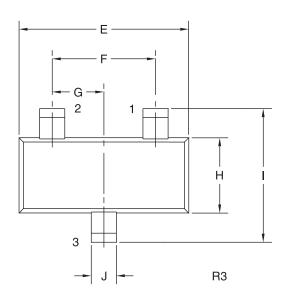
**HIGH VOLTAGE SILICON SWITCHING DIODES** 

**SURFACE MOUNT DUAL, IN SERIES** 

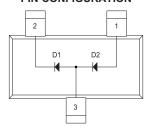


# **SOT-23 CASE - MECHANICAL OUTLINE**





# **PIN CONFIGURATION**



#### **LEAD CODE:**

- 1) Anode D2
- 2) Cathode D1
- 3) Anode D1, Cathode D2

MARKING CODES: CMPD2005S: DB5

CMPD2005SG\*: 5SG

DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
Α	0.003	0.007	0.08	0.18			
В	0.006	-	0.15	-			
С	-	0.005	-	0.13			
D	0.035	0.043	0.89	1.09			
E	0.110	0.120	2.80	3.05			
F	0.075		1.90				
G	0.037		0.95				
Н	0.047	0.055	1.19	1.40			
	0.083	0.098	2.10	2.49			
J	0.014	0.020	0.35	0.50			

SOT-23 (REV: R3)

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R3 (25-January 2010)

# **OUTSTANDING SUPPORT AND SUPERIOR SERVICES**



#### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

#### **DESIGNER SUPPORT/SERVICES**

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- · Special wafer diffusions
- · PbSn plating options
- Package details
- · Application notes
- · Application and design sample kits
- · Custom product and package development

#### **CONTACT US**

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